

Attorney Docket No.: AMD-H0552

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

bearing F of deposi	irst Ćlass Po	is transmittal of the below de estage and addressed to the	scribed docum Commissioner	for Patents P.	eposited with the United O. Box 1450, Alexandri	a, VA 22313-1450, (	on the below date						
Date of Deposit:	02/28/0	Name of Person Making the Deposit:	Shannon	Carmo	Signature of the Pers Making the Deposit:	on Mallula	Monu						
In re Application of: KHAN, et al.													
Application No.: 10/618,514 Examiner: KEBEDE, Brook													
Filed:	07/11/	2003		Art Unit: 2823									
Confirm	nation No	.: 6596											
For: METHOD OF FABRICATING SEMICONDUCTOR DEVICE HAVING TRIPLE LDD STRUCTURE AND LOWER GATE RESISTANCE FORMED WITH A SINGLE IMPLANT PROCESS													
P.O. B	ox 1450	or Patents 22313-1450	<u>AMEN</u>	IDMENT TI	RANSMITTAL								
1. Transmitted herewith is an amendment for this application													
Tr	( 11	I herewith is a respon sheets) I herewith are					plication.						
2. Applicant is other than a small entity													
Extension of Term													
3.	The proceedings herein are for a patent application and the provisions of 37 C.F.R. 1.136 apply.												
(a)	[ ] Applicant petitions for an extension of time under 37 C.F.R. 1.136 (fees: 37 C.F.R. 1.17(a)-(d) for the total number of months checked below:)												
<b>16</b> a.s		Extension [ ] one month [ ] two month [ ] three month [ ] four month [ ] five month	s ths is s	\$4 \$1 \$1 \$2 <b>F</b> •	20.00 50.00 ,020.00 ,590.00 ,160.00								
it an ac	iditional e	xtension of time is rec	juired, plea	ıse conside	r this a petition th	eretor.							

(b) [X] Applicant believes that no extension of term is required. However, this conditional petition is being made to provide for the possibility that applicant has inadvertently overlooked the need for a petition for extension of time.

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## Fee Calculation

4. The fee for claims (37 C.F.R. 1.16(b)-(d)) has been calculated as shown below:

(for other than a small entity)										
Fee Items	Claims Remaining After Amendment	Highest Number of Claims Previously Paid For	Present Extra Claims	Fee Rate	Total					
Total Claims	18	- 21 =		x \$50.00	\$0.00					
Independent Claims	2	- 3 =		x\$200.00	\$0.00					
Multiple Dependent Claim Fee (one or more, first added by this \$360.00 amendment)										
Total Fees										

## **PAYMENT OF FEES**

- 5. The full fee due in connection with this communication is provided as follows:
- [ x ] The Commissioner is hereby authorized to charge any additional fees associated with this communication or credit any overpayment to Deposit Account No.: 23-0085.

  A <u>duplicate copy</u> of this authorization is enclosed.

Please direct all correspondence concerning the above-identified application to the following address:

WAGNER, MURABITO & HAO LLP

Two North Market Street, Third Floor San Jose, California 95113 (408) 938-9060 Customer No:45592

Respectfully submitted,

Date: February 28, 2005

Jose S. Garcia

ED STATES PATENT AND TRADEMARK OFFICE

In re Application of: KHAN et al.

Serial No.

: 10/618,514

Group Art Unit: 2823

Filed

: 07/11/2003

Examiner: KEBEDE, B.

For

: METHOD OF FABRICATING SEMICONDUCTOR DEVICE

HAVING TRIPLE LDD STRUCTURE AND LOWER GATE

RESISTANCE FORMED WITH A SINGLE IMPLANT PROCESS

## AMENDMENT AND RESPONSE AFTER FINAL ACTION

Mail Stop AF Commissioner for Patents P.O Box 1450 Alexandria, VA 22313-1450

Sir:

In response to the Final Office Action mailed 12/28/2004, please enter and consider the following amendments and arguments for the above captioned patent application.

Amendments to the Claims are reflected in the listing of claims, which begins on page 2 of this paper.

Remarks/Arguments begin on page 9 of this paper.

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Group Art Unit: 2823